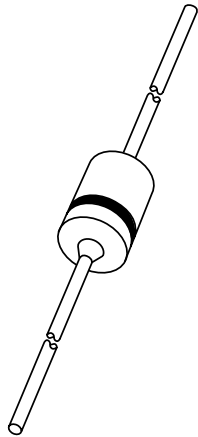


# DATA SHEET



## **1N914; 1N914A; 1N914B** High-speed diodes

Product specification  
Supersedes data of 1999 May 26

2003 Jun 06

## High-speed diodes

## 1N914; 1N914A; 1N914B

## FEATURES

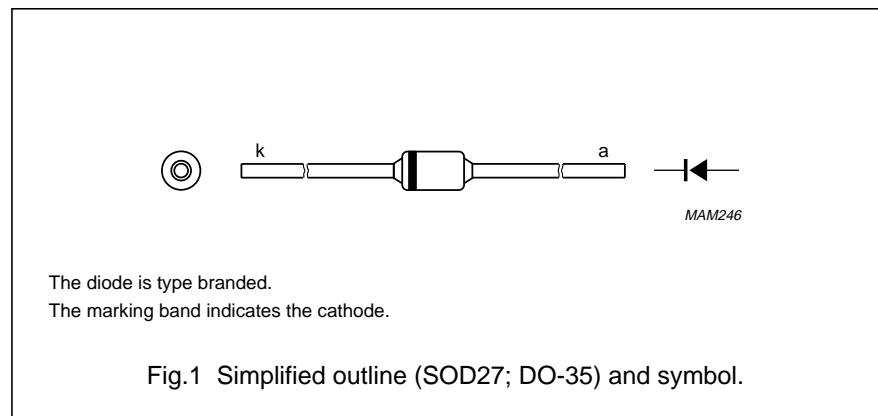
- Hermetically sealed leaded glass SOD27 (DO-35) package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 100 V
- Repetitive peak forward current: max. 225 mA.

## APPLICATIONS

- High-speed switching.

## DESCRIPTION

The 1N914, 1N914A and 1N914B are high-speed switching diodes fabricated in planar technology, and encapsulated in a hermetically sealed leaded glass SOD27 (DO-35) package.



## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage		–	100	V
$V_R$	continuous reverse voltage		–	75	V
$I_F$	continuous forward current	see Fig.2; note 1	–	75	mA
$I_{FRM}$	repetitive peak forward current		–	225	mA
$I_{FSM}$	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\ \mu\text{s}$ $t = 1\ \text{ms}$ $t = 1\ \text{s}$	–	4 1 0.5	A A A
$P_{tot}$	total power dissipation	$T_{amb} = 25\text{ °C}$ ; note 1	–	250	mW
$T_{stg}$	storage temperature		–65	+200	°C
$T_j$	junction temperature		–	175	°C

## Note

1. Device mounted on an FR4 printed-circuit board; lead length 10 mm.

## High-speed diodes

## 1N914; 1N914A; 1N914B

**ELECTRICAL CHARACTERISTICS** $T_j = 25\text{ }^\circ\text{C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage	see Fig.3			
	1N914; 1N914A	$I_F = 10\text{ mA}$	–	1	V
	1N914B	$I_F = 5\text{ mA}$	0.62	0.72	V
	1N914B	$I_F = 100\text{ mA}$	–	1	V
$I_R$	reverse current	see Fig.5			
		$V_R = 20\text{ V}$	–	25	nA
		$V_R = 75\text{ V}$	–	5	$\mu\text{A}$
		$V_R = 20\text{ V}; T_j = 150\text{ }^\circ\text{C}$	–	50	$\mu\text{A}$
$C_d$	diode capacitance	$f = 1\text{ MHz}; V_R = 0$ ; see Fig.6	–	4	pF
$t_{rr}$	reverse recovery time	when switched from $I_F = 10\text{ mA}$ to $I_R = 10\text{ mA}$ ; $R_L = 100\ \Omega$ ; measured at $I_R = 1\text{ mA}$ ; see Fig.7	–	8	ns
		when switched from $I_F = 10\text{ mA}$ to $I_R = 60\text{ mA}$ ; $R_L = 100\ \Omega$ ; measured at $I_R = 1\text{ mA}$ ; see Fig.7	–	4	ns
$V_{fr}$	forward recovery voltage	when switched from $I_F = 50\text{ mA}$ ; $t_r = 20\text{ ns}$ ; see Fig.8	–	2.5	V

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length 10 mm; note 1	500	K/W

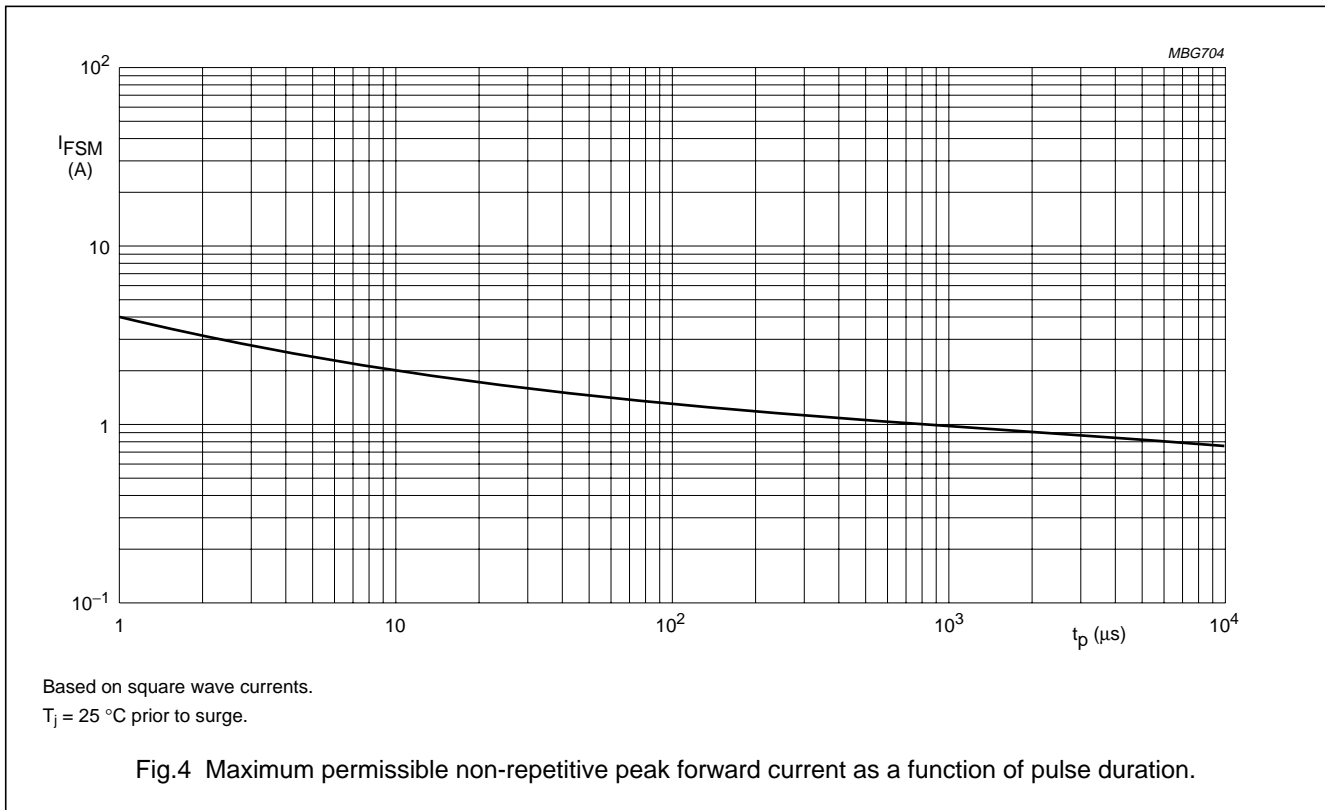
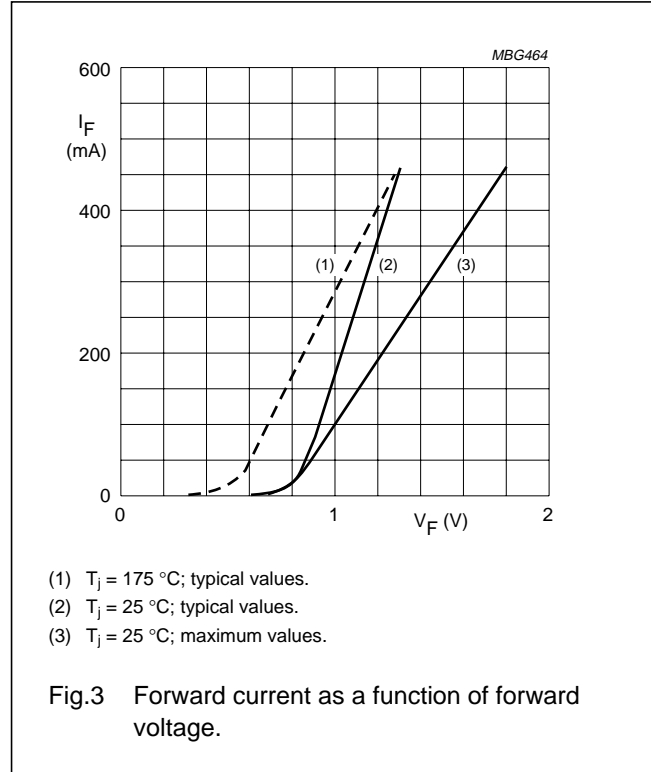
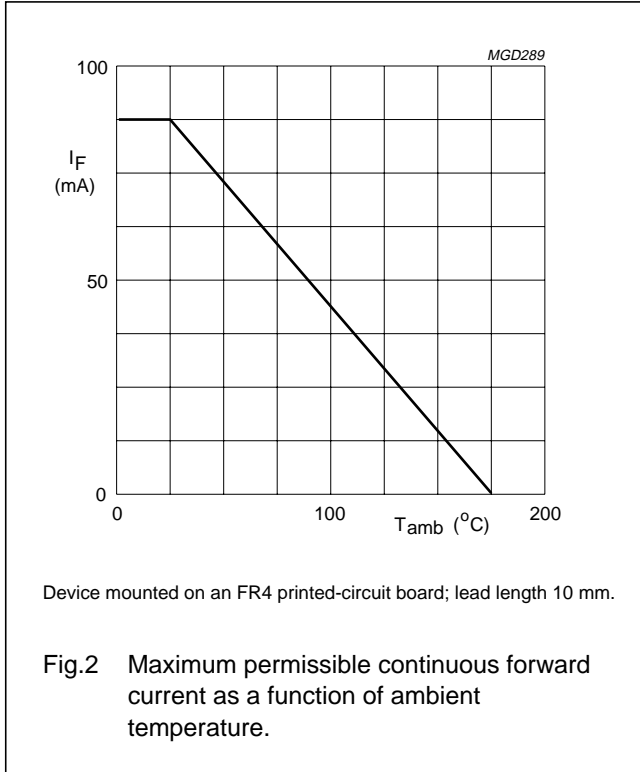
**Note**

1. Device mounted on a printed-circuit board without metallization pad.

High-speed diodes

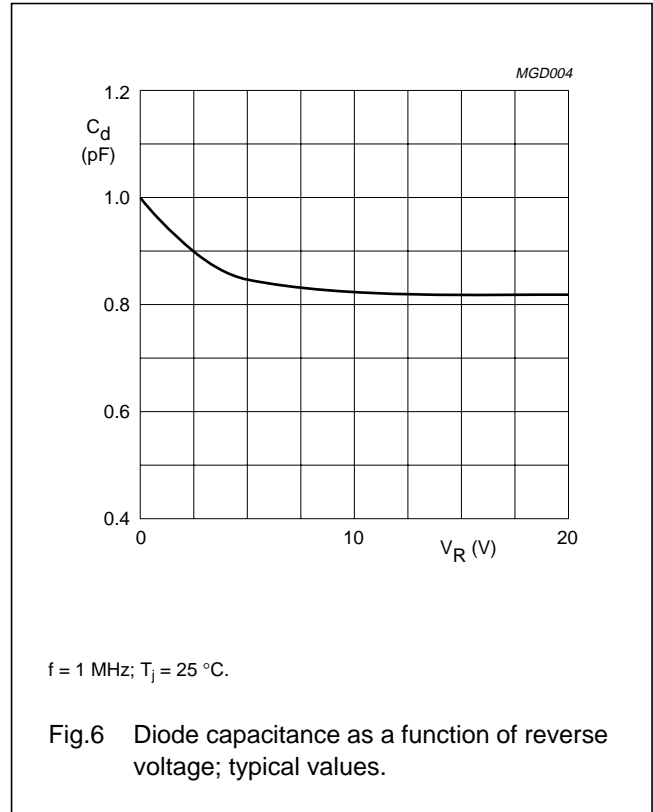
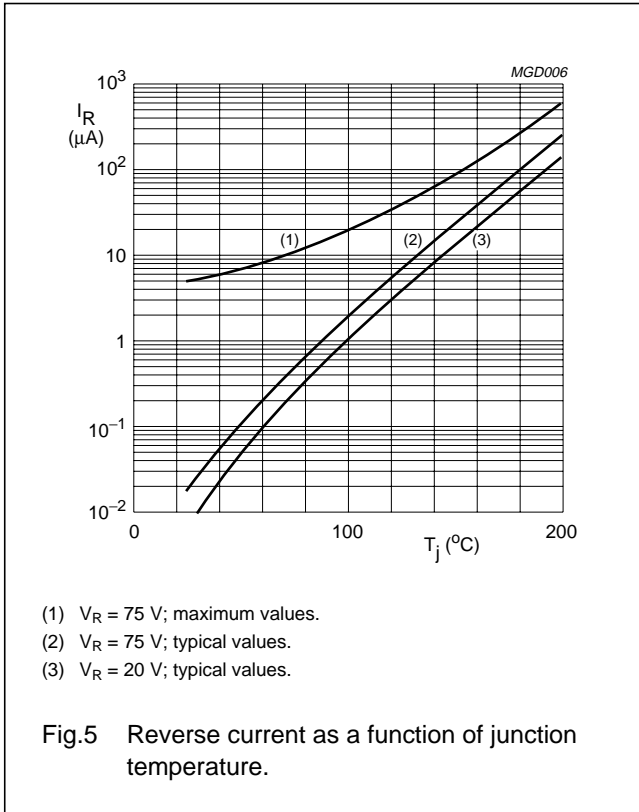
1N914; 1N914A; 1N914B

GRAPHICAL DATA



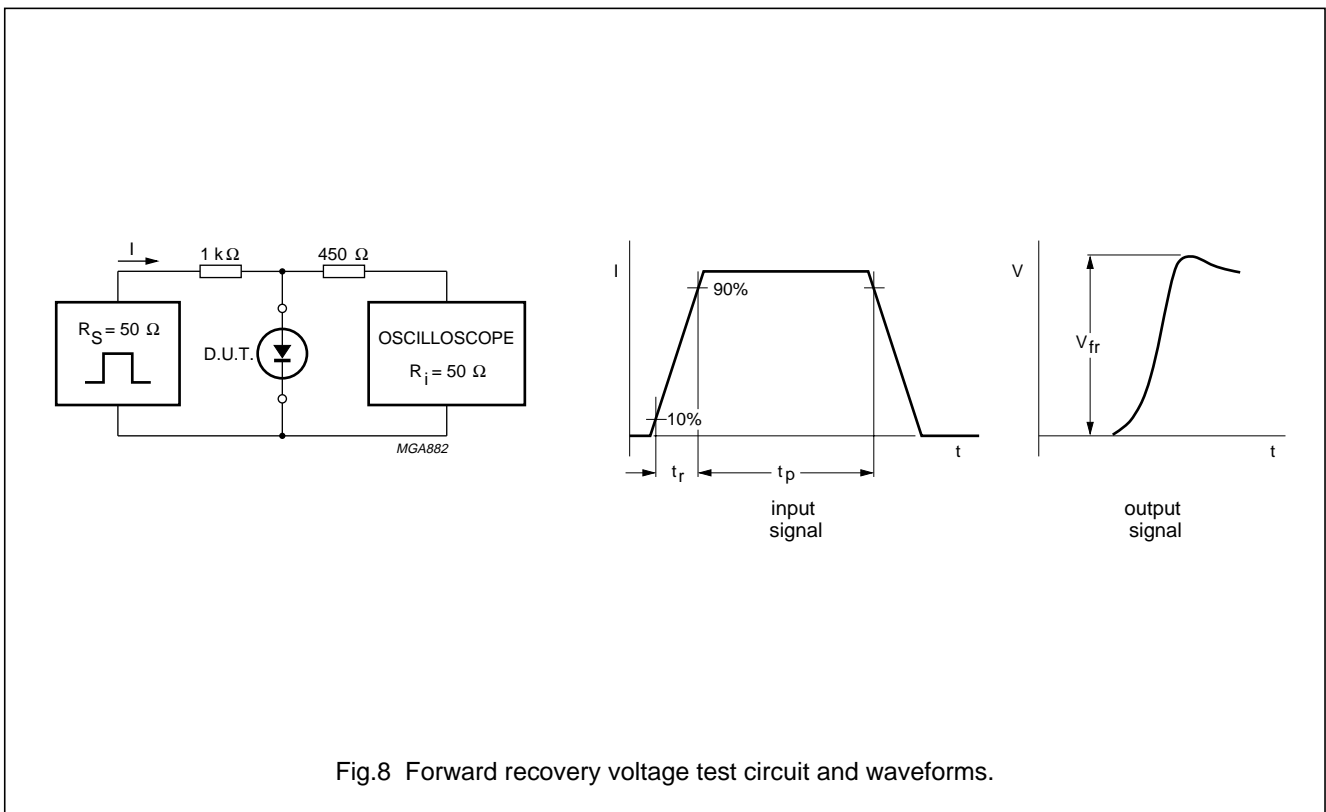
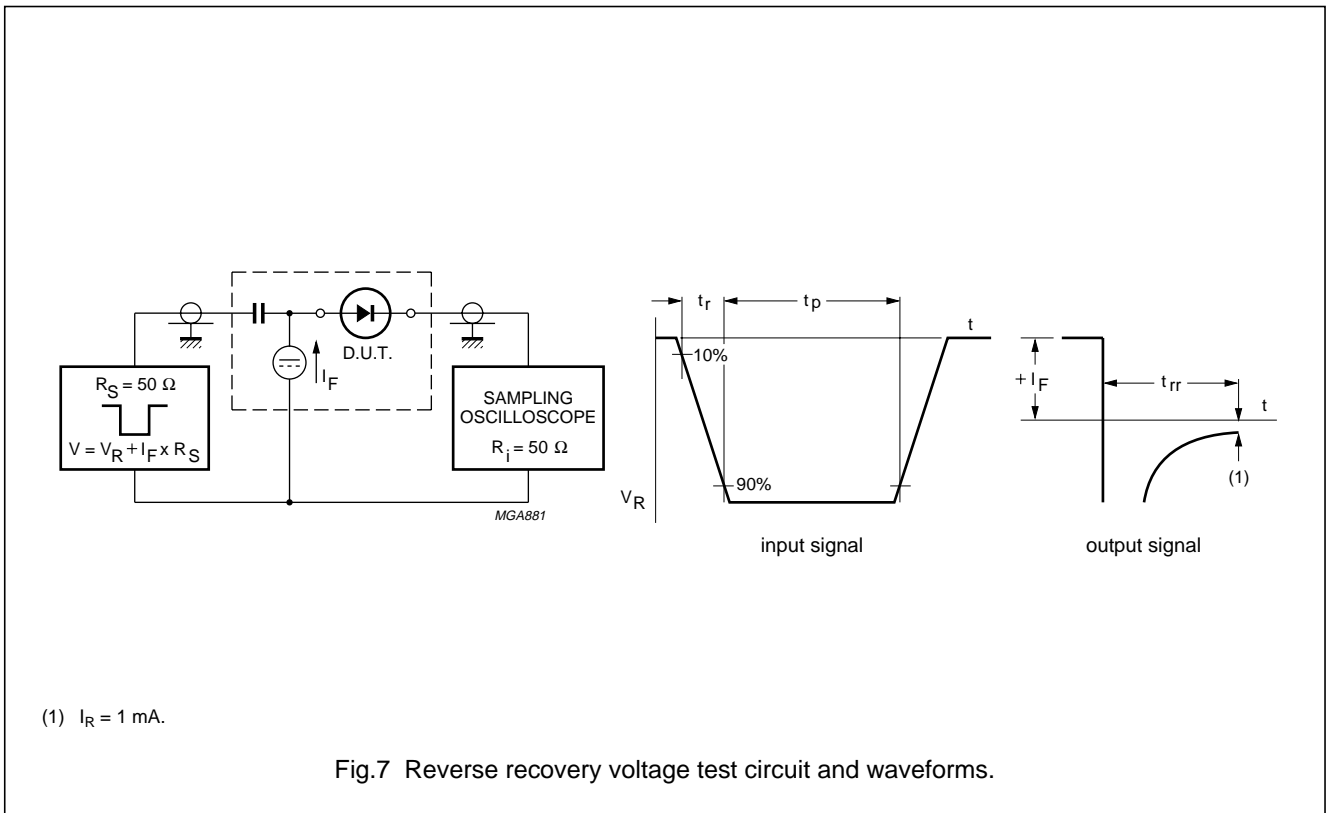
High-speed diodes

1N914; 1N914A; 1N914B



High-speed diodes

1N914; 1N914A; 1N914B



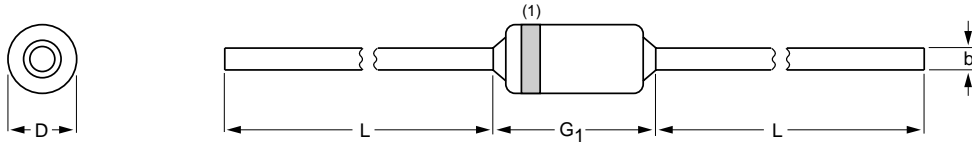
High-speed diodes

1N914; 1N914A; 1N914B

PACKAGE OUTLINE

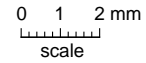
Hermetically sealed glass package; axial leaded; 2 leads

SOD27




DIMENSIONS (mm are the original dimensions)

UNIT	b max.	D max.	G <sub>1</sub> max.	L min.
mm	0.56	1.85	4.25	25.4



Note

1. The marking band indicates the cathode.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOD27	A24	DO-35	SC-40			97-06-09

## High-speed diodes

1N914; 1N914A; 1N914B

## DATA SHEET STATUS

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)(3)</sup>	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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High-speed diodes

1N914; 1N914A; 1N914B

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**NOTES**

High-speed diodes

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**NOTES**

High-speed diodes

1N914; 1N914A; 1N914B

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**NOTES**

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